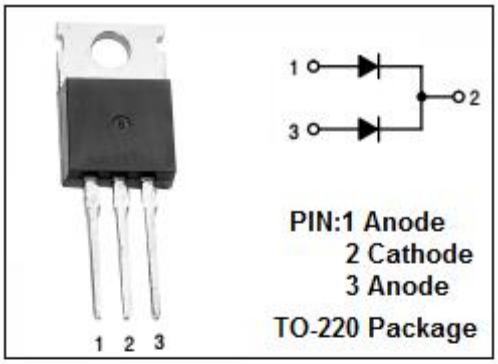
# Schottky Barrier Rectifier SBR3045CT

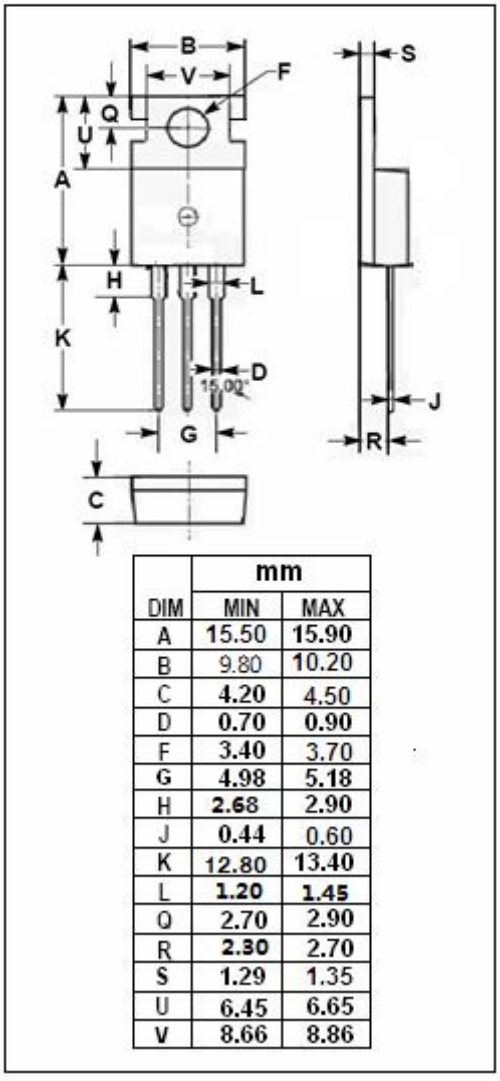



## FEATURES

- With TO-220 packaging
- High junction temperature capability
- Low forward voltage drop
- High current capability
- Low power loss, high efficiency
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

- Switching power supply
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration




| DIM | mm MIN | mm MAX |
|---|---|---|
| A | 15.50 | 15.90 |
| B | 9.80 | 10.20 |
| C | 4.20 | 4.50 |
| D | 0.70 | 0.90 |
| F | 3.40 | 3.70 |
| G | 4.98 | 5.18 |
| H | 2.68 | 2.90 |
| J | 0.44 | 0.60 |
| K | 12.80 | 13.40 |
| L | 1.20 | 1.45 |
| Q | 2.70 | 2.90 |
| R | 2.30 | 2.70 |
| S | 1.29 | 1.35 |
| U | 6.45 | 6.65 |
| V | 8.66 | 8.86 |

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|---|---|---|---|
| $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | 45 | V |
| $I_{F(AV)}$ | Average Rectified Forward Current@Tc=130℃ | 30 | A |
| $I_{FSM}$ | Nonrepetitive Peak Surge Current （8.3ms single half sine-wave superimposed on rated load conditions）tp=5μs sine | 200 | A |
| $T_J$ | Junction Temperature | 150 | ℃ |
| $T_{stg}$ | Storage Temperature Range | -65~150 | ℃ |

# Schottky Barrier Rectifier SBR3045CT

## THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---|---|---|---|
| $R_{th\ j\text{-}c}$ | Thermal Resistance,Junction to Case | 2 | ℃/W |

## ELECTRICAL CHARACTERISTICS (Pulse Test: Pulse Width=300 μ s,Duty Cycle≤1%)

| SYMBOL | PARAMETER | CONDITIONS | MAX | UNIT |
|---|---|---|---|---|
| $V_F$ | Maximum Instantaneous Forward Voltage | $I_F$= 15A ; Tc= 25℃ | 0.55 | V |
| | | $I_F$= 15A ; Tc= 25℃ | 0.5 | |
| $I_R$ | Maximum Instantaneous Reverse Current | $V_R$= $V_{RWM;}$Tc= 25℃ | 0.5 | mA |
| | | $V_R$= $V_{RWM;}$Tc= 100℃ | 100 | |